

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013

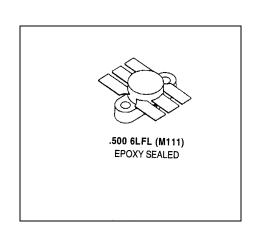
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### MS1527

# RF & MICROWAVE TRANSISTORS UHF COMMUNICATIONS APPLICATIONS

#### **Features**

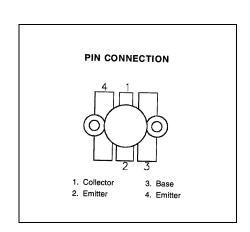
- 400 MHz
- 28 VOLTS
- P<sub>OUT</sub> = 25 WATTS
- G<sub>P</sub> = 9 dB GAIN MINIMUM
- EMITTER BALLASTED
- METAL/CERAMIC PACKAGE
- INTERNAL INPUT MATCHING
- REFRACTORY/GOLD METALIZATION



### **DESCRIPTION:**

The MS1527 is a gold metallized epitaxial silicon NPN planar transistor using diffused emitter ballast resistors for superior ruggedness.

The MS1527 can withstand 20:1 VSWR under rated operating conditions and is internally input matched to optimize power gain and efficiency over the band.



## **ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)**

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	3.5	V
Ic	Device Current	3.0	Α
P <sub>DISS</sub>	Power Dissipation	70	W
Τ <sub>J</sub>	Junction Temperature	+200	°C
T <sub>STG</sub>	Storage Temperature	-65 +150	°C

## **Thermal Data**

R <sub>TH(J-C)</sub>	Thermal Resistance Junction-case	2.5	°C/W	





# **ELECTRICAL SPECIFICATIONS (Tcase = 25°C) STATIC**

Symbol	Test Conditions		Value			
Symbol	Symbol rest conditions		Min.	Typ.	Max.	Unit
BV <sub>CBO</sub>	I <sub>C</sub> = 50 mA	$I_E = 0mA$	60			V
BV <sub>EBO</sub>	I <sub>E</sub> = 5 mA	$I_C = 0 \text{ mA}$	3.5			V
BV <sub>CES</sub>	$I_C = 50 \text{ mA}$	$V_{BE} = 0 V$	60			V
I <sub>CBO</sub>	V <sub>CB</sub> = 30 V	$I_E = 0 \text{ mA}$			3.0	mA
HFE	V <sub>CE</sub> = 5 V	$I_C = 500 A$	10	30	120	

### **DYNAMIC**

Symbol	mbol Test Conditions		Value			Unit	
Syllibol			Min.	Typ.	Max.	Onit	
P <sub>out</sub>	f = 400 MHz	$V_{CC} = 28 V$	Pin = 3.15W	25			w
ης	f = 400 MHz	$V_{CC} = 28 \text{ V}$		50	55		%
G <sub>P</sub>	f = 400 MHz	$V_{CC} = 28 V$		9.0	10.5		dB
VSWR	f = 400 MHz	$V_{CC} = 28 \text{ V}$		20:1			
Сов	f = 1 MHz	V <sub>CB</sub> = 28V				30	pF

# **IMPEDANCE DATA**

FREQ	$Z_IN(\Omega)$	$Z_{CL}(\Omega)$
225 MHz	1.40 + j 2.5	7.55 + j 0.0
275 MHz	1.25 + j 3.3	7.5 - j 0.05
300 MHz	1.10 + j 4.0	7.5 - j 1.00
350 MHz	1.10 + j 4.7	6.8 - j 1.15
400 MHz	1.70 + j 5.1	6.0 - j 1.30

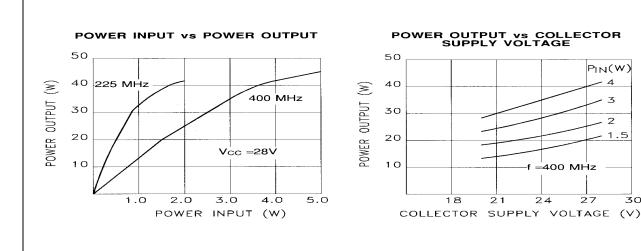
 $P_{OUT} = 25 W$  $V_{CE} = 28 V$ 



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# **TYPICAL PERFORMANCE**







### PACKAGE MECHANICAL DATA

